

Application Data Sheet

Inventor Information

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Application Information

Title Line One: REFERENCE VOLTAGE GENERATION THE
Title Line Two: CIRCUIT FOR SEMICONDUCTOR MEMORY
Title Line Three: DEVICE, MEMORY READING CIRCUIT
Title Line Four: INCLUDING SAME, AND ELECTRONIC
Title Line Five: INFORMATION DEVICE INCLUDING THE SAME
Total Drawing Sheets: 14
Formal Drawings?: Yes
Application Type: Utility
Docket Number: 299002054200

Representative Information

Representative Customer Number: 25226

Continuity Information

This application is a:

> Application One:

Filing Date:

which is a:

>>Application Two:

Filing Date:

which is a:

>>>Application Three:

Filing Date:

Prior Foreign Applications

Foreign Application One:

2001-057499

Filing Date:

March 1, 2001

Country:

Japan

Priority Claimed:

Yes